

Kinetically-controlled thin-film growth of layered β - and γ - Na_xCoO_2 cobaltate

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Abstract

We report growth characteristics of epitaxial β - $\text{Na}_{0.6}\text{CoO}_2$ and γ - $\text{Na}_{0.7}\text{CoO}_2$ thin films on (001) sapphire substrates grown by pulsed-laser deposition. Reduction of deposition rate could change structure of Na_xCoO_2 thin film from β -phase with island growth mode to γ -phase with layer-by-layer growth mode. The γ - $\text{Na}_{0.7}\text{CoO}_2$ thin film exhibits spiral surface growth with multiterraced islands and highly crystallized texture compared to that of the β - $\text{Na}_{0.6}\text{CoO}_2$ thin film. This heterogeneous epitaxial film growth can give opportunity of strain effect of physical properties and growth dynamics of Na_xCoO_2 as well as subtle nature of structural change.

Families of sodium cobalt oxide Na_xCoO_2 are attractive materials due to their large thermoelectric power and low resistivity, which can be applied for thermoelectric applications[1, 2]. The large thermoelectric power is attributed to the spin entropy from the low-spin state of Co ion[3]. Occurrence of superconductivity of $\text{Na}_{0.35}\text{CoO}_2 \cdot 1.3\text{H}_2\text{O}$ with T_C about 5 K and rich phase diagrams of Na_xCoO_2 with respect to x also inspire many theoretical and experimental interests of novel ground states due to its two-dimensional transition-metal oxide triangular lattice[4].

Until now, physical properties of single crystal and powder of Na_xCoO_2 have been widely studied[5, 6, 7, 8, 9] but there have been no rigorous reports about thin film studies of Na_xCoO_2 . Since the thin film is interesting in its own due to strain effect as well as the fact that most application can be done in thin film structure, the thin film growth of Na_xCoO_2 can give an opportunity of manipulation of physical properties by changing strain field using different substrates and growth parameters (substrate temperature, oxygen partial pressure, etc). In this study, we report the thin film growth of differently structured epitaxial Na_xCoO_2 by Pulsed Laser Deposition (PLD) on (001) sapphire.

The crystal structure of Na_xCoO_2 consists of two-dimensional triangular CoO_2 layers of edge-sharing CoO_6 octahedra separated by an insulating layer of Na^+ ions. There are four known phases of Na_xCoO_2 with slightly different structures such as α -, α' -, β -, and γ - phases of Na_xCoO_2 distinguished by stacking order of CoO_2 layers and Na-O environments. Figure 1 shows schematic structures of β - Na_xCoO_2 and γ - Na_xCoO_2 in a-c plane. The β -phase has a monoclinic unit cell with a space group symmetry of C2/m and lattice constants of $a = 4.902$, $b = 2.828$, $c = 5.720 \text{ \AA}$ and $\beta = 105.96^\circ$. The γ -phase has a hexagonal structure with a space group symmetry of $\text{P6}_3/\text{mmc}$ and lattice constants of $a = 2.840$ and $c = 10.811 \text{ \AA}$ [10, 11, 12]. In γ - Na_xCoO_2 , in-plane direction of CoO_6 octahedron in CoO_2 layer is alternating with the nearest CoO_2 layers, whereas, in β - Na_xCoO_2 , the direction is parallel with the nearest CoO_2 layers. These structural varieties of Na_xCoO_2 imply that the bulk modulus along the plane is small and the stress is an important parameter for the growth of the epitaxial thin films because of various possible stacking structures of CoO_2 layer and possibility of stacking fault as seen in bulk Na_xCoO_2 .

Na_xCoO_2 thin films have been grown by PLD method. The $\text{Na}_{0.8}\text{CoO}_2$ target, which was used in PLD, was prepared by a conventional solid-state reaction method. Na_2CO_3 (99.995 %) and Co_3O_4 (99.998 %) were mixed in molar ratio of Na : Co = 0.8 : 1.0 and the mixed

powder was pressed into pellet and calcined at 750°C for 12 h. The calcined pellet was reground, pressed into pellet, and sintered at 850°C for 24 h. (001) sapphire substrate was used for the thin film growth and the substrate temperature of optimal thin film growth was 480°C. A frequency tripled (355 nm, ~ 2 J/cm²) Nd:YAG laser was used for the deposition and the distance between target and substrate was ~ 4 cm. The deposition rates in the range of 0.02 $\sim$ 0.2 Å /pulse were controlled by repetition of laser pulse and an eclipse method, in which a shadow mask was placed between the target and the substrate. The energy of an adatom was reduced by the eclipse method because direct high-energy particles would be rejected by the shadow mask. Optimal oxygen pressure of 400 mTorr was maintained during the deposition.

The γ -Na_{0.7}CoO₂ thin film was grown with layer-by-layer growth mode by the low deposition rate of 0.02 Å /pulse using the eclipse method on (001) sapphire substrates. When the deposition rate was increased, the mixed phase of β - and γ -Na_xCoO₂ was observed. By the condition of the high deposition rate of 0.2 Å /pulse, only the β -Na_{0.6}CoO₂ thin film was grown with island growth mode. For the structural determinations of β - and γ -Na_xCoO₂ thin films, x-ray diffraction data were obtained by conventional laboratory x-ray as well as synchrotron x-ray sources at 5C2 in Pohang Light Source. The thicknesses of β - and γ -Na_xCoO₂ thin films were ~ 1000 and ~ 2000 Å, respectively, determined from the cross-sectional images of scanning electron microscope (SEM). The tentative compositions of β -Na_{0.6}CoO₂ and γ -Na_{0.7}CoO₂ were obtained by energy dispersive x-ray spectrometer (EDS). The surface morphologies and topographies of β -Na_{0.6}CoO₂ and γ -Na_{0.7}CoO₂ thin films were observed by SEM and atomic force microscope (AFM).

Figure 2 (a) shows the x-ray diffraction pattern of the epitaxially grown (00 l) β -Na_{0.6}CoO₂ thin film on (001) sapphire substrate. The full width at half maximum (FWHM) of the (001) rocking curve is about 1.4°. The out-of-plane lattice constant of 5.459 Å was obtained from the (00 l) peaks and this value is slightly smaller than that of bulk β -Na_xCoO₂. To check the in-plane orientation, we performed x-ray scattering with Φ -scan geometry. Figure 2 (b) shows Φ -scan of ($\bar{1}12$) peak of β -Na_{0.6}CoO₂ thin film and (104) peak of the sapphire substrate. The ($\bar{1}12$) peaks of β -Na_{0.6}CoO₂ thin film are located 30° off from the (104) plane of sapphire substrate. The sixfold symmetry of ($\bar{1}12$) peaks from the twinned grains is observed, representing that the a-lattice of β -Na_{0.6}CoO₂ thin film is oriented along the hexagonal symmetry of a-axis lattice of (001) sapphire substrate. The FWHM of in-plane

($\bar{1}12$) peak is equal to 1.3° . From the 2θ values of the (111) and the ($\bar{1}12$) peaks, we obtain a monoclinic a-axis lattice constant of $4.886 \text{ \AA}$ and b-axis lattice constant of $2.818 \text{ \AA}$ that are close to the bulk lattice constant ($a = 4.902$, $b = 2.828 \text{ \AA}$) of $\beta\text{-Na}_{0.6}\text{CoO}_2$. To check a strain of the film, h , k , and l scans near the ($\bar{1}12$) plane were performed. The data indicated that the strain along the in-plane direction was low estimated from the small FWHM of h , k scans and the strain along the out-of-plane direction was high resulting from the large FWHM of l scan. To investigate the growth rate effects, we have grown Na_xCoO_2 thin film on (001) sapphire substrates using the same target with the low deposition rate of $0.02 \text{ \AA/pulse}$ by the eclipse method.

Figure 3 (a) shows the x-ray diffraction pattern of the epitaxially grown (00 l) $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film on (001) sapphire substrate. The FWHM of the (002) rocking curve is about 0.8° and this FWHM of $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film is smaller than that of $\beta\text{-Na}_{0.6}\text{CoO}_2$ thin film, indicating that the (00 l) $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film shows better crystallized texture along the out-of-plane direction. The c-lattice constant of $10.848 \text{ \AA}$ was obtained from the (002) peak. Figure 3 (b) shows Φ -scan of (104) peak of the epitaxial $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin films and (104) peak of the (001) sapphire substrate. The sixfold symmetry represents the hexagonal structure of $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film with twins. The FWHM of in-plane (104) peak is equal to 0.6° and this indicates that the $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film also shows better crystallized texture along the in-plane direction than that of the $\beta\text{-Na}_{0.6}\text{CoO}_2$ thin film. From the 2θ value of (104) peak, we obtain a hexagonal a-axis lattice constant of $2.812 \text{ \AA}$ that is similar to the bulk $\gamma\text{-Na}_{0.7}\text{CoO}_2$. Thus, $\gamma\text{-Na}_{0.7}\text{CoO}_2$ film grown by the low deposition condition shows better-crystallized texture both in-plane and out-of-plane direction.

Figure 4 (a) and (b) show the AFM images of epitaxial $\beta\text{-Na}_{0.6}\text{CoO}_2$ and $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin films, respectively. The large grains with typical tetrahedral islands are observed in $\beta\text{-Na}_{0.6}\text{CoO}_2$ thin film. The shape indicates that the diffusion length along the surface is short during deposition and the kinetics of the step is limited locally resulting from the high deposition rate. The root mean square (rms) surface roughness has the large value of $220 \text{ \AA}$ (Figure 4 (c) and (d)). However, the spiral patterns with multi-terraces are observed in $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film, and this indicates that epitaxial $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film was grown with atomically flat surface by monolayer steps. The surface roughness of $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film is extremely smooth with the rms roughness of $8 \text{ \AA}$. Figure 4 (e) and (f) show the sectional contour graphs of the #1-line and the #2-line in $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film. The large

terraces with a width of $1000 \sim 2000 \text{ \AA}$ are observed and the terrace heights are nearly half or same of one lattice unit along the c-axis. This large width of the terraces represents that the surface diffusion of adatoms along the surface is long enough and the kinetics of the step is widespread due to the low deposition rate inhibiting from frequent nucleation of adatoms[13]. Therefore, $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film shows layer-by-layer growth following the ideal step flow growth mode, closely.

In conclusion, we have grown the epitaxial $\beta\text{-Na}_{0.6}\text{CoO}_2$ and $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin films on the (001) sapphire substrate deposited by PLD method. On the low deposition rate of $0.02 \text{ \AA /pulse}$, the $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film was grown with layer-by-layer growth. When a deposition rate was increased, a mixed phase of β - and $\gamma\text{-Na}_x\text{CoO}_2$ was observed. By the condition of the high deposition rate of $0.2 \text{ \AA /pulse}$, the $\beta\text{-Na}_{0.6}\text{CoO}_2$ thin film was grown with tetrahedral islands. The $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin film exhibits spiral surface growth with multi-terraces and highly crystallized texture. These experimental demonstrations and controllability could provide opportunities of strain effects of Na_xCoO_2 and physical properties of thin films and growth dynamics of heterogeneous epitaxial thin films.

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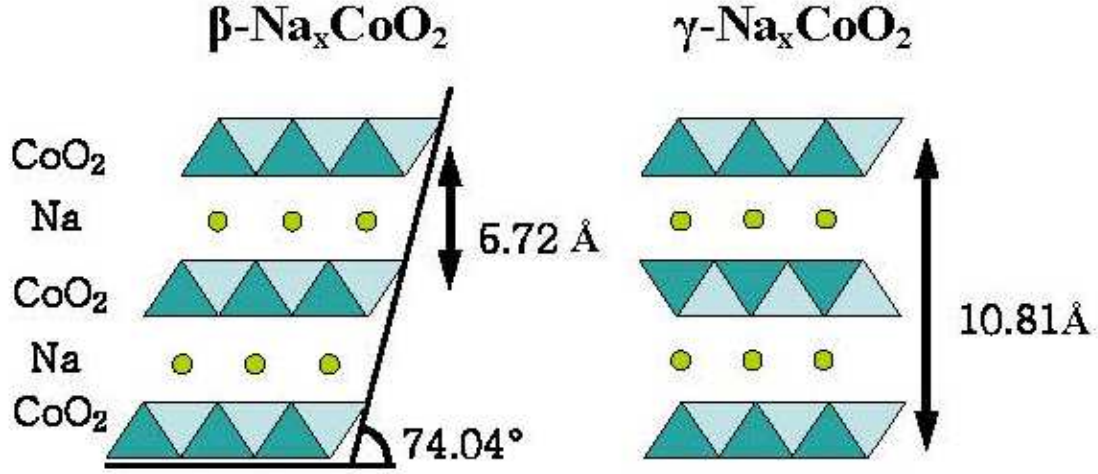


FIG. 1: Schematic structures of $\beta\text{-Na}_x\text{CoO}_2$ and $\gamma\text{-Na}_x\text{CoO}_2$. Rhombus and filled circle symbolizes a CoO_6 octahedron and Na ions, respectively. $\beta\text{-Na}_x\text{CoO}_2$ has a monoclinic structure with $\beta = 105.96^\circ$. In $\gamma\text{-Na}_x\text{CoO}_2$, in-plane direction of CoO_6 octahedron in CoO_2 layer has the opposite direction of in-plane direction of CoO_6 octahedron in the nearest CoO_2 layers.

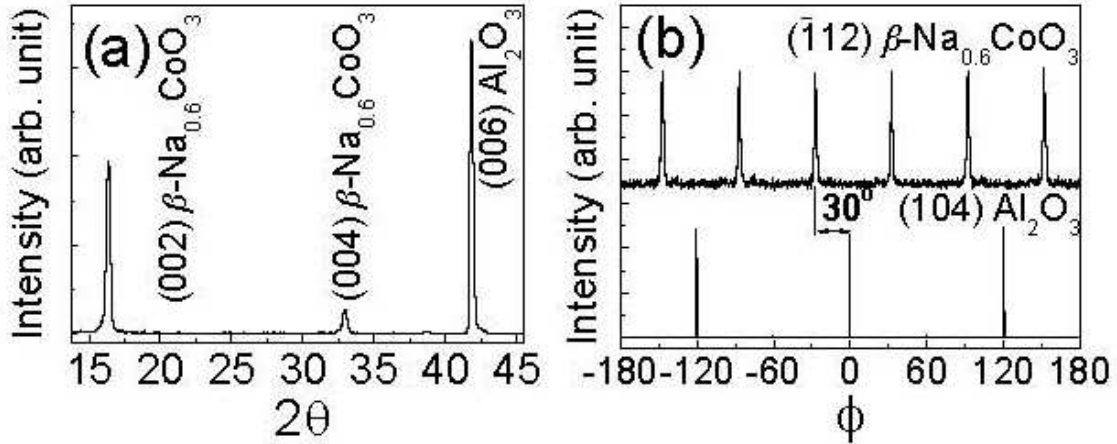


FIG. 2: (a) X-ray diffraction pattern of the epitaxial $\beta\text{-Na}_{0.6}\text{CoO}_2$ thin films. (b) Φ -scan of $(\bar{1}12)$ peaks of the epitaxial $\beta\text{-Na}_{0.6}\text{CoO}_2$ thin films and (104) peaks of (001) sapphire substrate.

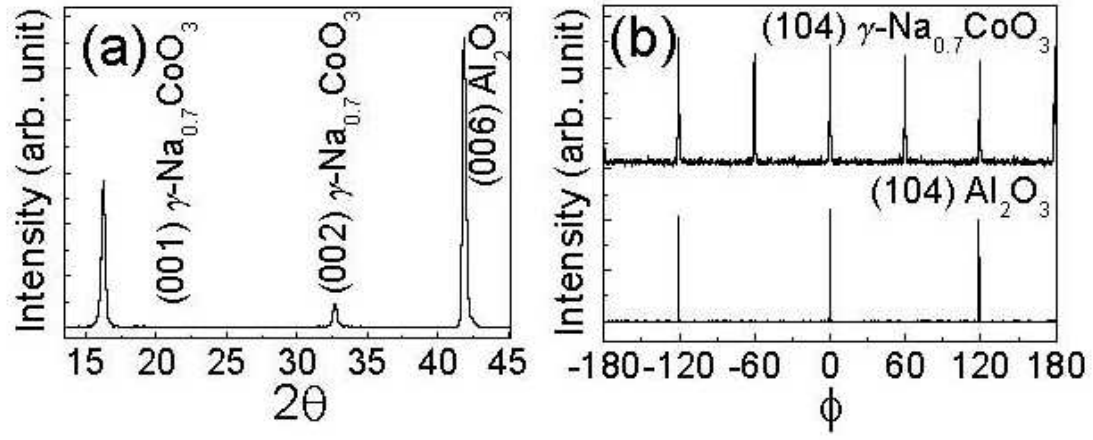


FIG. 3: (a) X-ray diffraction pattern of the epitaxial $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin films. (b) Φ -scan of (104) peaks of the epitaxial $\gamma\text{-Na}_{0.7}\text{CoO}_2$ thin films and (104) peaks of (001) sapphire substrate.

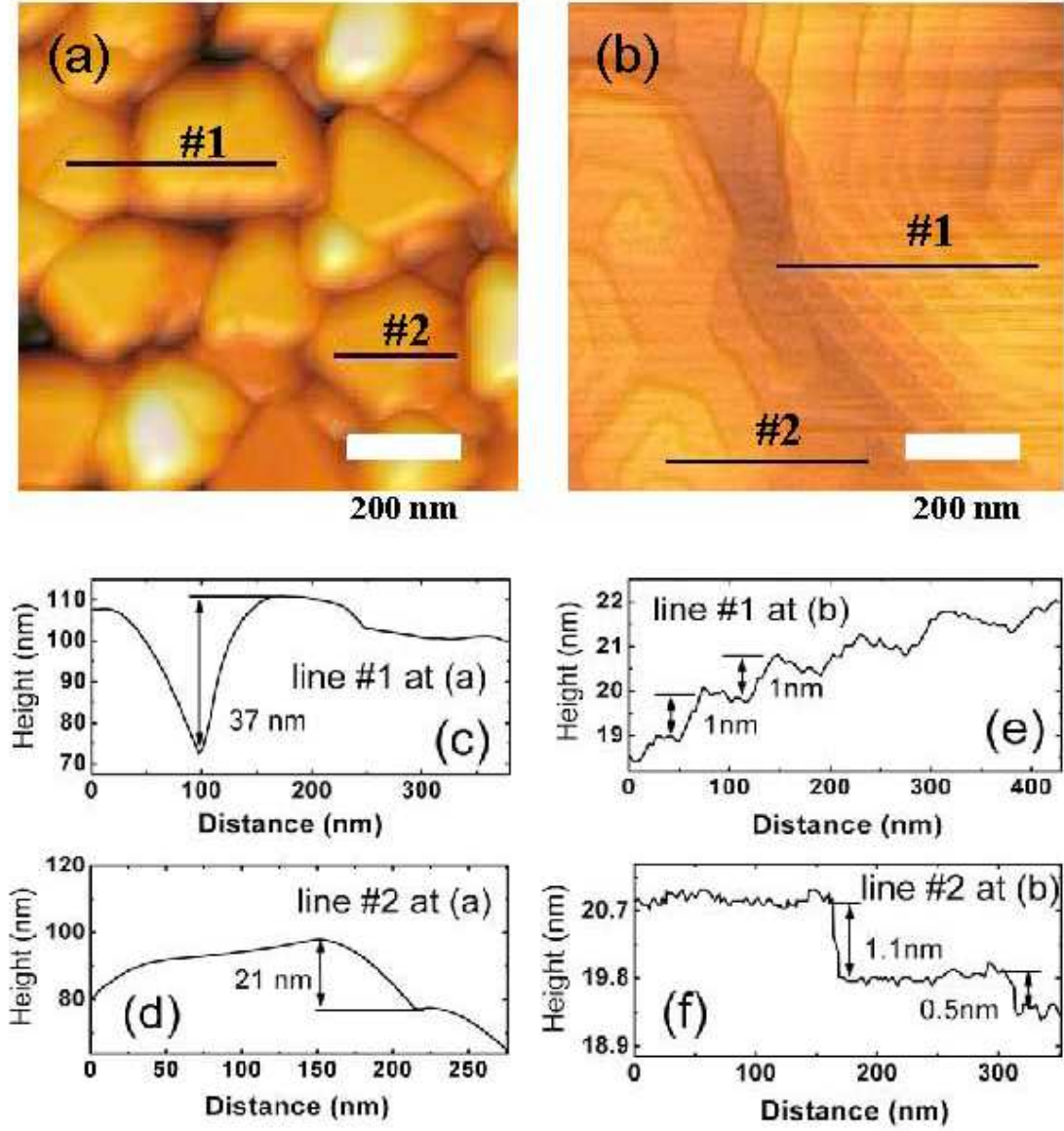


FIG. 4: AFM images of (a) β - $\text{Na}_{0.6}\text{CoO}_2$ thin film and (b) γ - $\text{Na}_{0.7}\text{CoO}_2$ thin film. Sectional contour graph of (c) the #1-line in β - $\text{Na}_{0.6}\text{CoO}_2$ thin film, (d) the #2-line in β - $\text{Na}_{0.6}\text{CoO}_2$ thin film, (e) the #1-line in γ - $\text{Na}_{0.7}\text{CoO}_2$ thin film, (f) the #2-line in γ - $\text{Na}_{0.7}\text{CoO}_2$ thin film. The γ - $\text{Na}_{0.7}\text{CoO}_2$ thin film shows spiral surface growth with multi-terraces. The terrace heights in (e) and (f) are nearly half or same of one lattice unit.